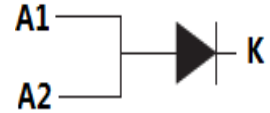


Main Product Characteristics:

IF	5A
VRRM	150V
Tj(max)	150°C
Vf(max)	0.8V



TO263
SSBD5L150A



Schematic Diagram

Features and Benefits:

- High Junction Temperature
- High ESD Protection
- High Forward & Reverse Surge capability



Description:

Schottky Barrier Rectifier designed for high frequency switch model power supplies such as adaptors and DC/DC converters; this product special design for high forward and reverse surge capability

Absolute Rating:

Symbol	Characterizes	Value	Unit
VRRM	Peak Repetitive Reverse Voltage	150	V
VR(RMS)	RMS Reverse Voltage	105	V
IF(AV)	Average Forward Current	5	A
IFSM	Non Repetitive Surge Forward Current(tp=8.3ms sinusoidal)	150	A
IRRM	Peak Repetitive Reverse Surge Current(Tp=2us)	2	A
TJ	Maximum operation Junction Temperature Range	-55~150	°C
Tstg	Storage Temperature Range	-55~150	°C

Thermal Resistance

Symbol	Characterizes	Value	Unit
RθJC	Maximum Thermal Resistance Junction To Case (per leg)	TO263 2	°C/W

Electrical Characterizes @TA=25°C unless otherwise specified

Symbol	Characterizes	Min	Typ	Max	Unit	Test Condition
VR	Reverse Breakdown Voltage	150			V	IR=0.5mA
VF	Forward Voltage Drop			0.8	V	IF=5A, TJ=25°C
				0.7		IF=5A, TJ=125°C
IR	Leakage Current			0.1	mA	VR=150V, TJ=25°C
				10		VR=150V, TJ=125°C

I-V Curves:

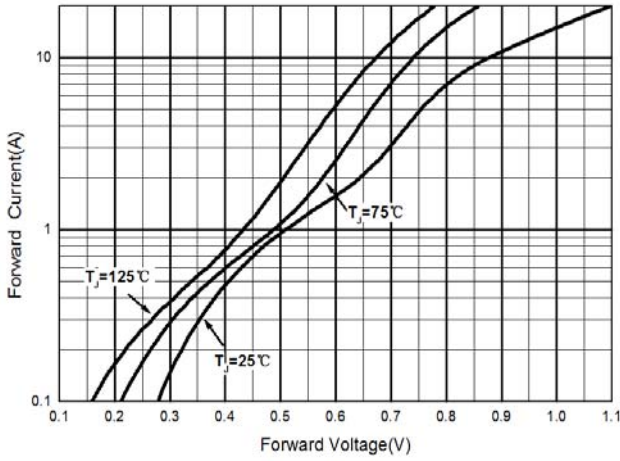


Figure 1: Typical Forward Characteristics

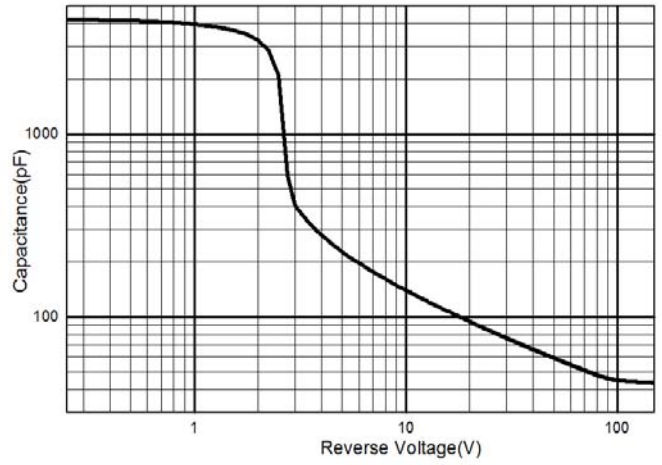


Figure 2: Typical Capacitance Characteristics

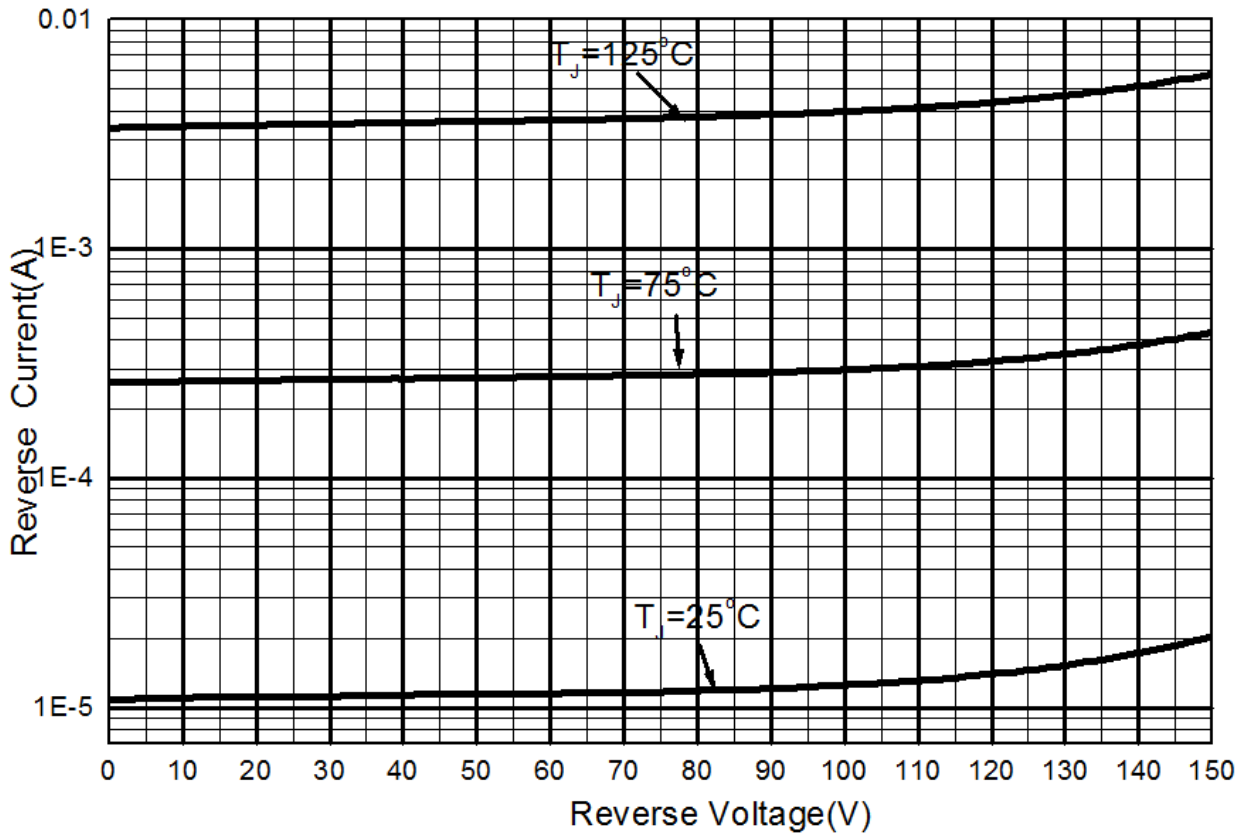
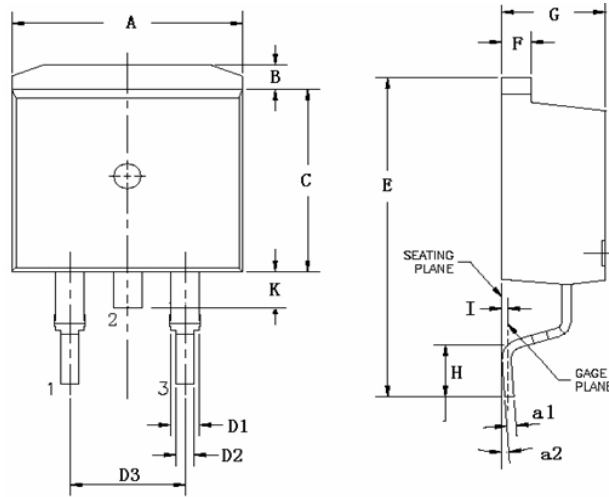


Figure 3: Typical Reverse Characteristics

Mechanical Data:

TO263:



Symbol	Dimension In Millimeters		Dimension In Inches	
	Min	Max	Min	Max
A	9.660	10.280	0.380	0.405
B	1.020	1.320	0.040	0.052
C	8.590	9.400	0.338	0.370
D1	1.140	1.400	0.045	0.055
D2	0.700	0.950	0.028	0.037
D3	5.080 (TYP)		0.200 (TYP)	
E	15.090	15.390	0.594	0.606
F	1.150	1.400	0.045	0.055
G	4.300	4.700	0.169	0.185
H	2.290	2.790	0.090	0.110
I	0.250 (TYP)		0.010 (TYP)	
K	1.300	1.600	0.051	0.063
a1	0.450	0.650	0.018	0.026
a2	0°	80	1°	8°

Ordering and Marking Information

Device Marking: SSBD5L150A

Package (Available)
TO263
Operating Temperature Range
C : -55 to 150 °C

Devices per Unit

Package Type	Units/Tube	Tubes/Inner Box	Units/Inner Box	Inner Boxes/Carton Box	Units/Carton Box
TO263	50	20	1000	6	6000

Reliability Test Program

Test Item	Conditions	Duration	Sample Size
High Temperature Reverse Bias(HTRB)	Tj=125°C to 175°C @ 80% of Max VDSS/VCES/VR	168 hours 500 hours 1000 hours	3 lots x 77 devices

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